

Features:

7.0A, 650V, $R_{DS(on)(Typ)} = 1.2\Omega$ @ $V_{GS} = 10V$

Low Gate Charge

Low C_{rss}

100% Avalanche Tested

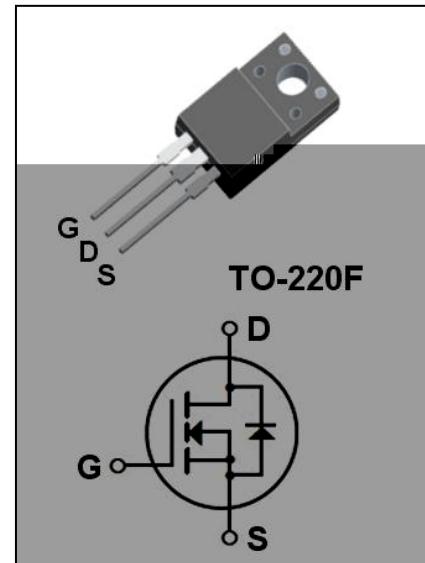
Fast Switching

Improved dv/dt Capability

Application:

High Frequency Switching Mode Power Supply

Active Power Factor Correction



Absolute Maximum Ratings ($T = 25^\circ C$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{DSS}	Drain-Source Voltage	650	V
I_D	Drain Current - Continuous ($T = 25^\circ C$)	7.0*	A
	- Continuous ($T = 100^\circ C$)	4.5*	A
I_{DM}	Drain Current - Pulsed (Note 1)	28*	A
V_{GSS}	Gate-Source Voltage	± 30	V
E_{AS}	Single Pulsed Avalanche Energy (Note 2)	590	mJ
I_{AR}	Avalanche Current (Note 1)	7.0	A
E_{AR}	Repetitive Avalanche Energy (Note 1)	14.0	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)	4.5	V/ns
P_D	Power Dissipation ($T_C = 25^\circ C$)	48	W
	-Derate above $25^\circ C$	0.38	W/ $^\circ C$
T_j	Operating Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature Range	-55 to +150	$^\circ C$

* Drain Current Limited by Maximum Junction Temperature.

Thermal Characteristics

Symbol	Parameter	Max	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case	2.6	$^\circ C / W$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	62.5	$^\circ C / W$

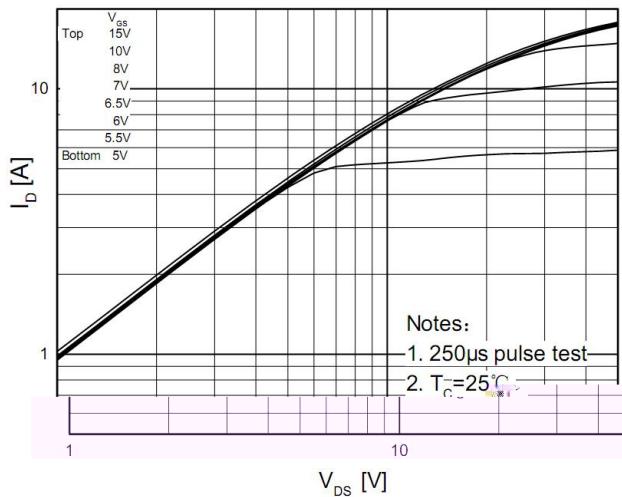
Electrical Characteristics(T =25°C unless otherwise noted)

Sym ol	Parameter	Test Conditons	Min	Typ	Max	Unit
Off Characteristics						
BV _{DSS}	Drain-sour e Breakdown Voltage	V _{GS} =0V ,I _D =250μA	650	--	--	V
△BV _{DSS} /△T _J	Breakdown Voltage Temperature Coeffi cient	I _D =250μA (Referen ed to 25°C)	--	0.7	--	V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =650V,V _{GS} =0V	--	--	1	μA
		V _{DS} =520V,T =125°C	--	--	10	μA
I _{GSSF}	Gate-Body Leakage Current,Forward	V _{GS} =+30V, V _{DS} =0V	--	--	100	nA
I _{GSSR}	Gate-Body Leakage Current,Reverse	V _{GS} =-30V, V _{DS} =0V	--	--	-100	nA
On Characteristics						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D =250μA	2.0	--	4.0	V
R _{DS(on)}	Stati Drain-Sour e On-Resistan e	V _{GS} =10 V, I _D =3.5A	--	1.2	1.4	Ω
g _{FS}	Forward Trans ondu tan e	V _{DS} =40 V, I _D =3.5A (Note4)	--	6.5	--	S
Dynamic Characteristics						
C _{iss}	Input Capa itan e	V _{DS} =25V,V _{GS} =0V, f=1.0MHz	--	1380	--	pF
C _{oss}	Output Capa itan e		--	170	--	pF
C _{rss}	Reverse Transfer Capa itan e		--	15	--	pF
Switching Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{DD} = 325 V, I _D = 7.0 A, R _G = 25 Ω (Note4,5)	--	13	--	ns
t _r	Turn-On Rise Time		--	100	--	ns
t _{d(off)}	Turn-Off Delay Time		--	126	--	ns
t _f	Turn-Off Fall Time		--	48	--	ns
Q _g	Total Gate Charge	V _{DS} = 520 V, I _D =7.0 A, V _{GS} = 10 V (Note4,5)	--	30	--	nC
Q _{gs}	Gate-Sour e Charge		--	6	--	nC
Q _{gd}	Gate-Drain Charge		--	14	--	nC
Drain-Source Diode Characteristics and Maximum Ratings						
I _S	Maximum Continuous Drain-Sour e Diode Forward Current	--	--	7.0	--	A
I _{SM}	Maximum Pulsed Drain-Sour e Diode Forward Current	--	--	28	--	A
V _{SD}	Drain-Sour e Diode Forward Voltage	V _{GS} =0V,I _S =7.0A	--	--	1.4	V
t _{rr}	Reverse Re overy Time	V _{GS} =0V, I _S =7.0A, d I _F /dt=100A/μs (Note4)	--	315	--	ns
	Reverse Re overy Charge		--	2.6	--	μC

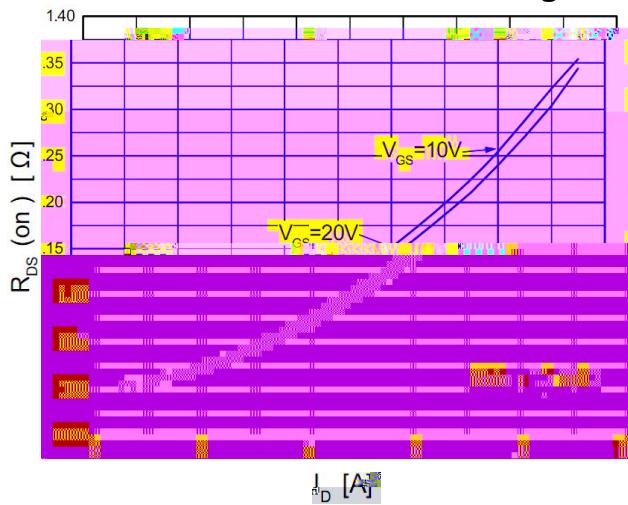
Notes:

- 1、Repetitive Rating:Pulse Width Limited by Maximum Junction Temperature.
- 2、L = 19.5mH, I_{AS} =7.0A, V_{DD} = 50V, R_G = 25 Ω, Starting T_J = 25°C.
- 3、I_{SD}≤7.0A, di/dt≤200A/μs, V_{DD}≤BV_{DSS}, Starting T_J = 25°C.
- 4、Pulse Test : Pulse Width ≤300 μ s, Duty Cy le≤2%.
- 5、Essentially Independent of Operating Temperature.

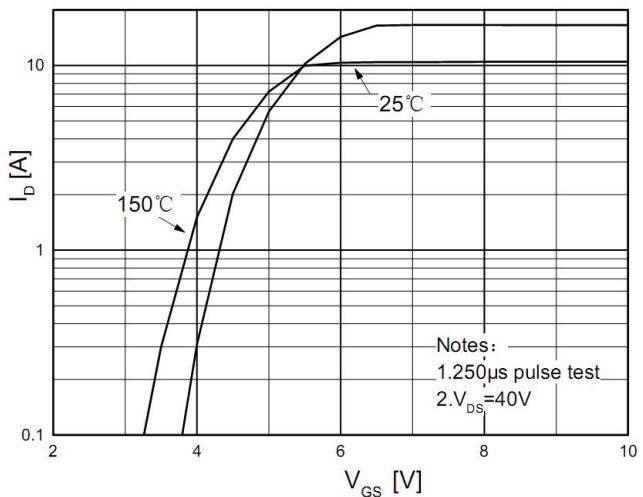
On-Region Characteristics



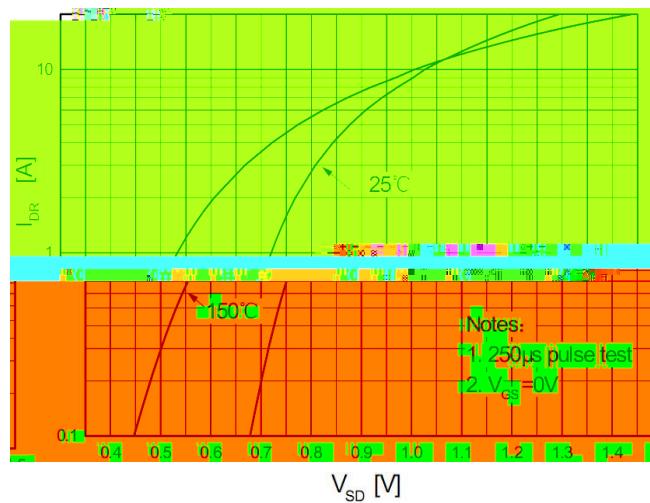
On-Resistance Variation vs. Drain Current and Gate Voltage



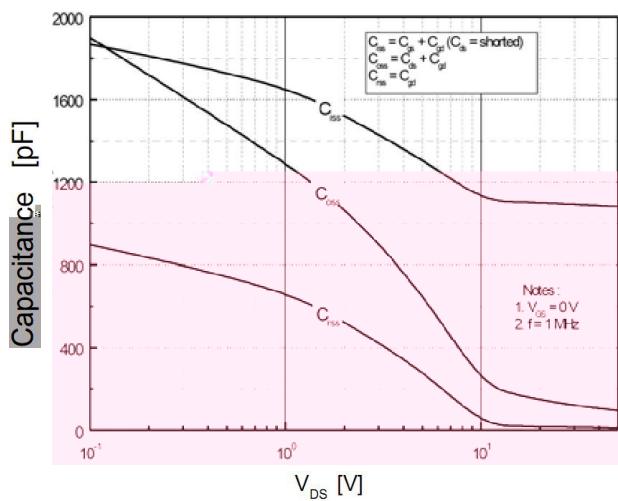
Transfer Characteristics



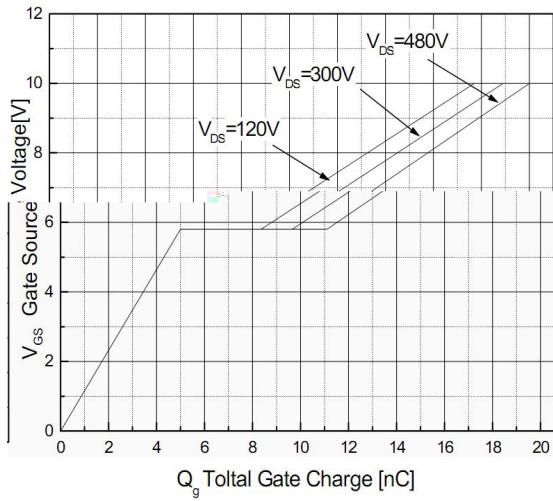
Body Diode Forward Voltage Variation vs. Source Current and Temperature



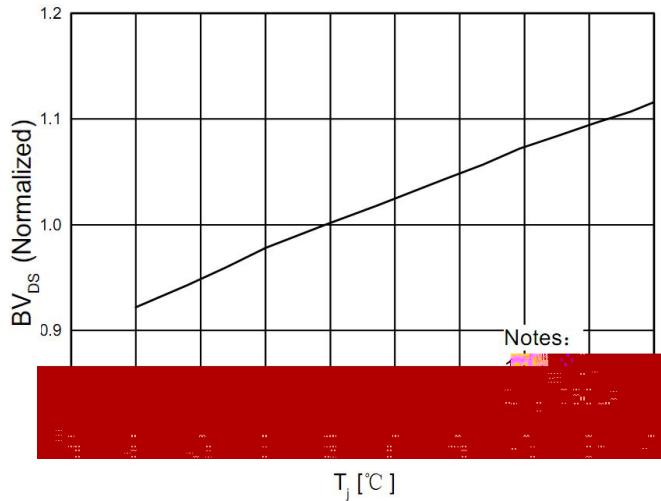
Capacitance Characteristics



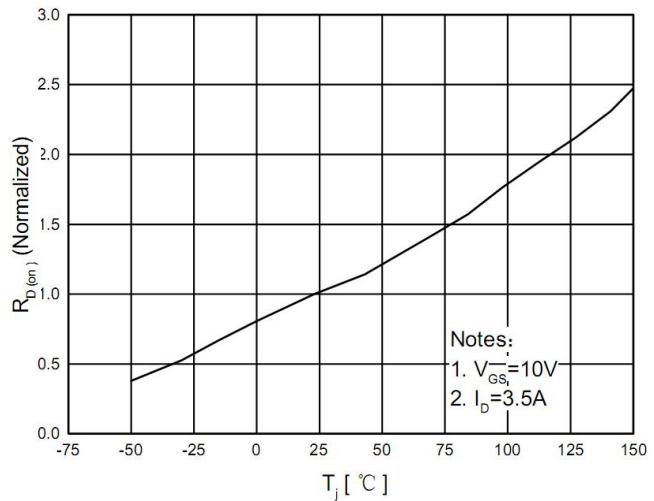
Gate Charge Characteristics



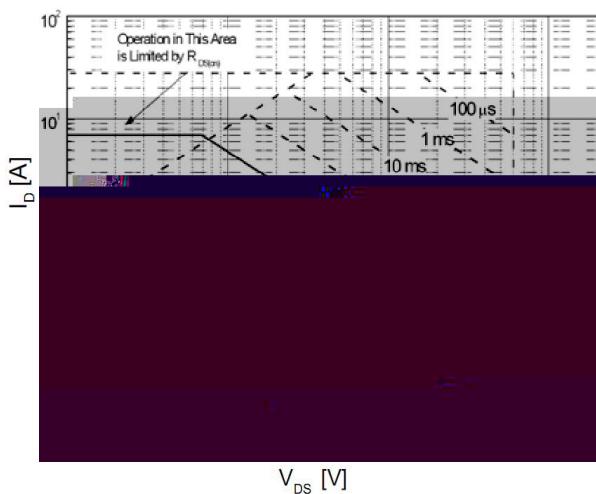
Breakdown Voltage Variation vs. Temperature



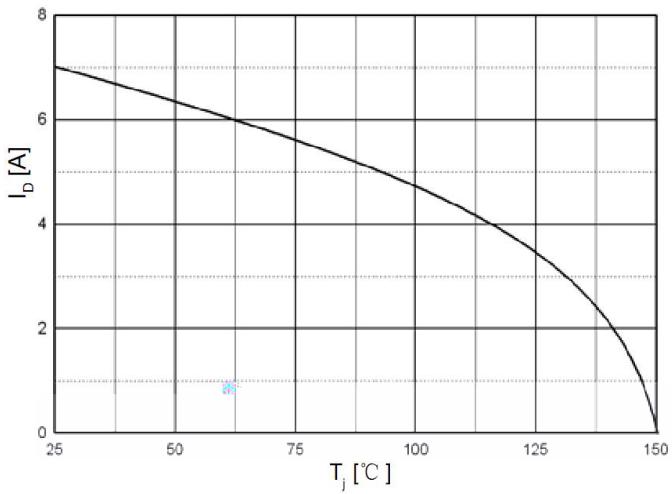
On-Resistance Variation vs. Temperature



Maximum Safe Operating Area



Maximum Drain Current Vs. Case Temperature



TO-220F Package Dimensions

UNIT: mm

SYMBOL	min	nom	max	SYMBOL	min	nom	max
A	9.80		10.60	D		2.54	
A1		7.00		D1	1.15		1.55
A2	2.90		3.40	D2	0.60		1.00
A3	9.10		9.90	D3	0.20		0.50
B1	15.40		16.40	E	2.24		2.84
B2	4.35		4.95	E1		0.70	
B3	6.00		7.40	E2		1.0 × 45°	
C	3.00		3.70	E3	0.35		0.65
C1	15.00		17.00	E4	2.30		3.30
C2	8.80		10.80				30°

